NSN 5961-01-326-2793

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-326-2793 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.040 inches and 0.050 inches **Overall Diameter:** Between 0.075 inches and 0.086 inches **Function For Which Designed:** Limiter **Mounting Method:** Press fit **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, dc and 180.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 1 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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